

NY9M008A

Single Channel 0.9A Motor Driver

Version 1.2

May 15, 2015



Revision History

Version	Date	Description	Modified Page
1.0	2014/04/16	New release.	-
1.1	2014/08/04	Update application circuit. Delete die form shipping and add Tape & Reel shipping.	7 9
1.2	2015/05/15	Modify motor current to 900mA. Update DC characteristics.	3, 4 6



1. 概述

NY9M008A 為單晶片CMOS的雙向馬達驅動IC,利用大型積體電路(LSI)製造技術,具有低電源及低成本的特性,可應用於低電壓工作模式。電路採用H橋架構,內置功率 MOSFET 開關,可實現對直流電機做正轉、反轉、煞車、停止四個功能的控制。

2. 功能

- (1). 寬廣的工作電壓: 1.8V~9.0V。
- (2). 內置 PMOS/NMOS 功率開關的 H 橋驅動器。
- (3). 支援4種操作模式:正轉/反轉/剎車/停止。
- (4). 低待機電流 (Typ.=0.1uA)。
- (5). 900mA 以上電流輸出能力。
- (6). 內建過溫保護功能。 (TSD, Thermal Shutdown)
- (7). CMOS 輸入,輸入腳內建下拉電阻,無需外加限流電阻。
- (8). 高達 5KV 的人體靜電模式 (HBM) 的 ESD 保護。
- (9). 提供 SOP-8 和 ESOP-8 封裝。

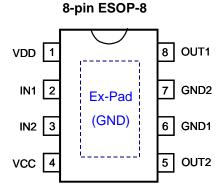
8-pin SOP-8

VDD 1 8 OUT1

IN1 2 7 GND2

IN2 3 6 GND1

VCC 4 5 OUT2



:外部焊墊。

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連接到PCB的接地散熱片以利散熱。



1. GENERAL DESCRIPTION

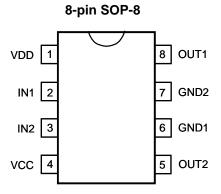
NY9M008A is a single-chip bi-directional motor driver CMOS IC for low-voltage applications. It is designed by LSI high technology with a low-power and low-cost process. It has H bridge driver of built-in MOSFET power switch to provide Forward / Reverse / Brake / Stop function for motor driver applications.

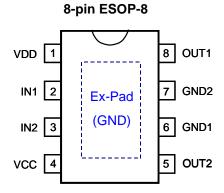
2. FEATURES

- (1). Wide operating voltage: 1.8V ~ 9.0V.
- (2). H bridge driver of internal PMOS/NMOS power switches.
- (3). Support 4 operating mode: Forward / Backward / Brake / Stop.
- (4). Low standby current. (Typ.=0.1uA)
- (5). Over 900mA output current capability.
- (6). Built-in Thermal Shutdown (TSD) circuit.
- (7). CMOS input. Built-in input pull-low resistance and no current-limit resistance required.

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- (8). High 5KV Human Body Mode (HBM) ESD protection.
- (9). SOP-8 and ESOP-8 package type are available.



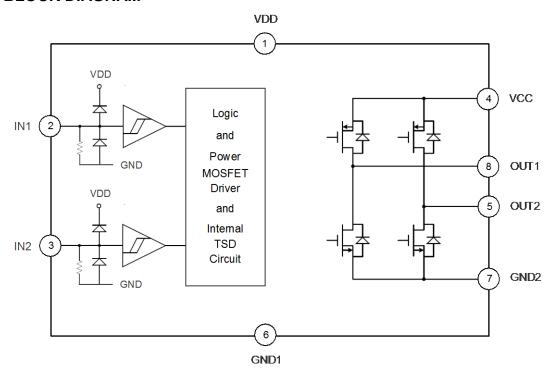


: Exposed Pad.

Connect to PCB ground plane for heat dissipation.



3. BLOCK DIAGRAM



4. PIN DESCRIPTION

Pin Name	Pin No.	ATTR.	Description	
IN1	2	I	Forward rotation logic input.	
IN2	3	I	Backward rotation logic input.	
OUT1	8	0	Forward rotation output.	
OUT2	5	0	Backward rotation output.	
VDD	1	Power	Positive power of logic control circuit.	
VCC	4	Power	Positive power of output power MOSFET.	
GND1	6	Power	Negative power of logic control circuit.	
GND2	7	Power	Negative power of output power MOSFET.	
Ex-Pad	9	Power	Exposed pad for thermal tab, must be connected to GND.	

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5. FUNCTION DESCRIPTION

IN1	IN2	OUT1	OUT2	Function		
0	0	Z (Off)	Z (Off)	Stop (Standby)		
1	0	1	0	Forward		
0	1	0	1	Backward		
1	1	0	0	Brake		



6. ELECTRICAL CHARACTERISTICS

6.1 Absolute Maximum Rating

Symbol	Parameter	•	Rating	Unit
V _{DD} - V _{SS}	Supply voltage of logic	control circuit	-0.5 ~ +7.5	V
V _{cc}	Supply voltage of output p	ower MOSFET	9.6	V
I _{OUT-PEAK}	Output peak cu	ırrent	2.0	А
Δ	Thermal resistance (Junction to Ambient)	SOP-8	150	°CAM
θ_{JA}		ESOP-8	60	°C/W
D	Power dissipation	SOP-8	0.9	10/
P_D		ESOP-8	2.3	W
T _A	Operating ambient te	emperature	-40 ~ +85	°C
TJ	Operating junction te	mperature	+160	°C
T _{ST}	Storage temper	ature	-55 ~ + 160	°C

6.2 DC Characteristics (VDD=3.0V, Vcc=6.0V, TA=25°C, unless otherwise specified)

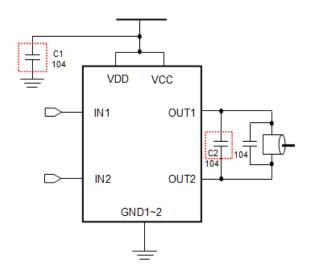
Symbol	Parameter		Min.	Тур.	Max.	Unit	Condition	
V_{DD}	Operating voltage (Logic)		1.8		6.8	V		
V_{CC}	Operating voltage (MOSFET)		1.8		9.0	V		
I _{SB}	Stand	lby current		0.1	1	uA	IN1=IN2=0	
	Operating	$V_{DD} = V_{CC} = 3.0V$		200		uA	IN1=1, IN2=0 or	
I _{OP}	current	$V_{DD} = V_{CC} = 6.0V$		270		uA	IN1=0, IN2=1 or IN1=1, IN2=1	
	Input high current (12kΩ pull-low resistance)			260		uA	V _{IH} = 3.0V	
I _{IH}				510		uA	V _{IH} = 6.0V	
V _{IH}	Input high voltage		0.7V _{DD}			V		
V _{IL}	Input low voltage				0.3V _{DD}	V		
	Output resistance (SOP-8 Package)			0.68		Ω	I _{OUT} = 500mA	
				0.77		Ω	I _{OUT} = 800mA	
Б				0.92		Ω	I _{OUT} = 1200mA	
R _{ON}	0 /			0.60		Ω	I _{OUT} = 500mA	
	Output resistance (ESOP-8 Package)			0.65		Ω	I _{OUT} = 800mA	
				0.79		Ω	I _{OUT} = 1200mA	
	Output continuous current (* with PCB heat dissipation)			900	1200*	mA	SOP-8	
I _{OUT}				1100	1600*	mA	ESOP-8	
I _{PULSE}	Pulsed drain current				5.0	Α	Pulse width < 20ms	
T _{RISE}	Output rise time			300		ns		
T _{FALL}	Output fall time			120		ns	PWM=20kHz, Duty=50%	
T _{RP}	Input-to-Outp	out response time		250		ns		
T _{TSD}	Thermal shutdown (TSD) Thermal shutdown hysteresis			160		°C	long affice to a good or	
T _{TSDH}				35		°C	Junction temperature	

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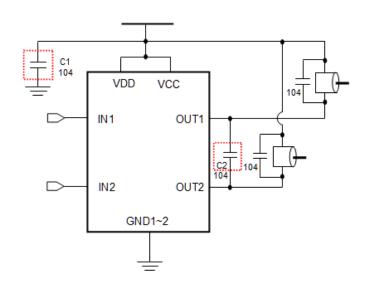


7. APPLICATION CIRCUIT

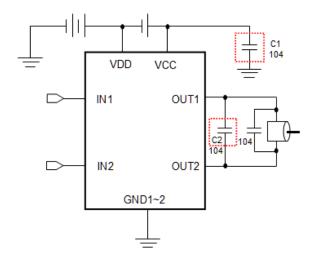
(1) One Motor Bi-Directional Control (Single Power)



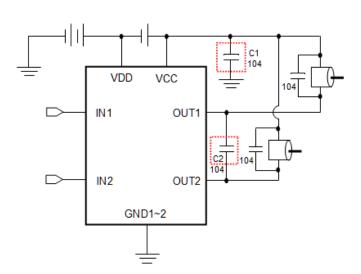
(2) Two Motors Directional Control (Single Power)



(3) One Motor Bi-Directional Control (Dual Power)



(4) Two Motors Directional Control (Dual Power)



^{*} In normal application, C1 (0.1uF) can be saved, but please reserve C1 space at PCB layout.

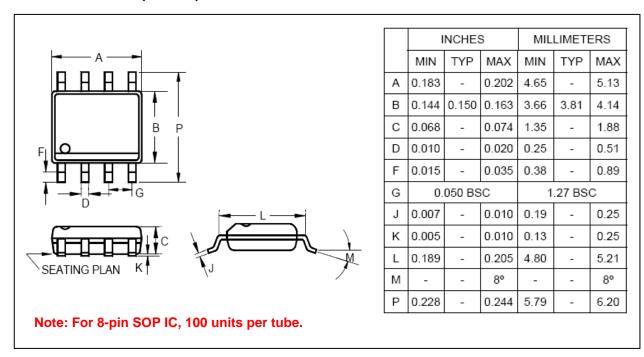
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^{*} If voltage is higher than 6.0V, C2 (0.1uF) is necessary to endure high voltage.

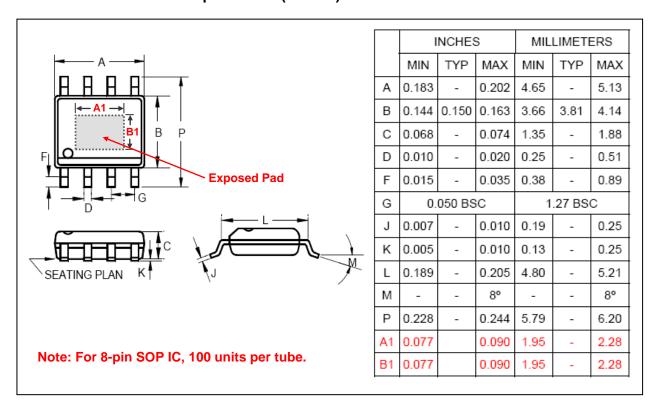


8. PACKAGE DIMENSION

8.1 8-Pin Plastic SOP (150 mil)



8.2 8-Pin Plastic ESOP with Exposed Pad (150 mil)



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9. ORDERING INFORMATION

P/N	Package Type	Package Width	Shipping
NY9M008AS8	SOP-8	150 mil.	Tape & Reel: 2.5K pcs per Reel
NY9M008AE8	ESOP-8	150 mil.	Tube: 100 pcs per Tube